NSN 5962-01-530-8848

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-530-8848

Body Length:
0.540 inches
Body Width:
0.300 inches
Body Height:
0.092 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Fwd fuselag f-15 aircraft
Features Provided:
Electrostatic sensitive and hermetically sealed and burn in and monolithic and positive outputs and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
F-9 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes forward current, peak total value not applicable
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, bipolar programable logic, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds delay
Memory Device Type:
Pal
Supplementary Features:
Make from pn 8103610sa cage 67268 programing with computer file pt50059108-02-01

20 flat leads

Terminal Type And Quantity:

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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